

SEMICONDUCTOR

# **MJD340**

## **High Voltage Power Transistors D-PAK for Surface Mount Applications**

- Lead Formed for Surface Mount Applications (No Suffix)
  Straight Lead (I-PAK, "- I" Suffix)



## **NPN Epitaxial Silicon Transistor**

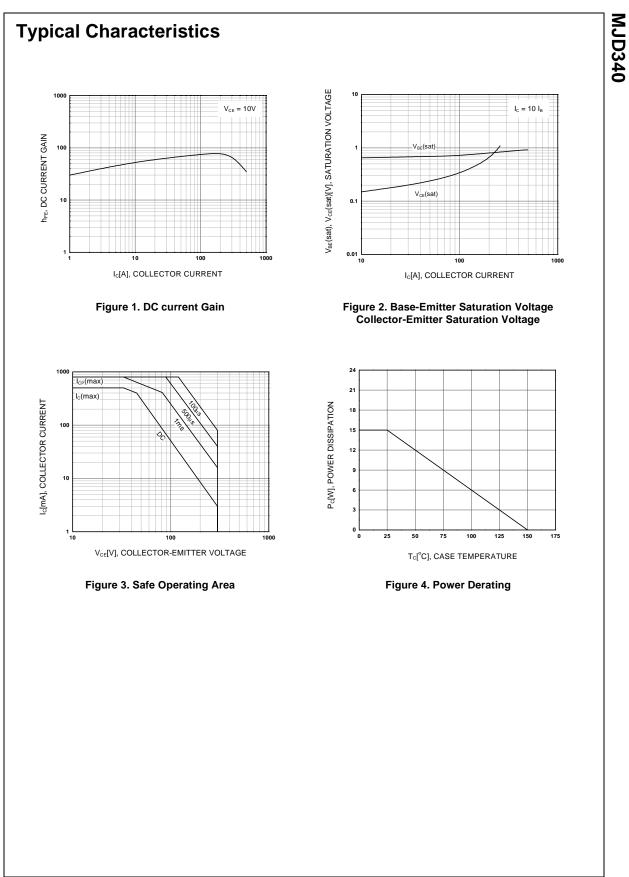
| Symbol           | Parameter                                    | Value      | Units |
|------------------|--|------------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage                       | 300        | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage                    | 300        | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage                         | 3          | V     |
| I <sub>C</sub>   | Collector Current (DC)                       | 0.5        | А     |
| I <sub>CP</sub>  | Collector Current (Pulse)                    | 0.75       | А     |
| P <sub>C</sub>   | Collector Dissipation (T <sub>C</sub> =25°C) | 15         | W     |
|                  | Collector Dissipation (T <sub>a</sub> =25°C) | 1.56       | W     |
| TJ               | Junction Temperature                         | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature                          | - 65 ~ 150 | °C    |

## Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

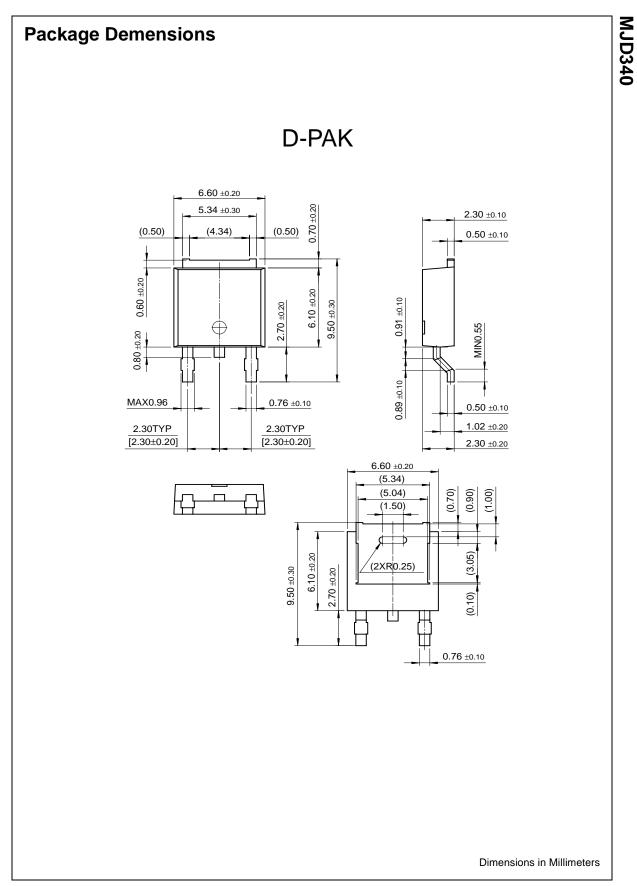
### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

| Symbol                 | Parameter                              | Test Condition                            | Min. | Max. | Units |
|------------------------|--|---|------|------|-------|
| V <sub>CEO</sub> (sus) | * Collector Emitter Sustaining Voltage | $I_{\rm C} = 1 {\rm mA}, \ I_{\rm B} = 0$ | 300  |      | V     |
| I <sub>CEO</sub>       | Collector Cut-off Current              | V <sub>CB</sub> = 300V, I <sub>E</sub> =0 |      | 0.1  | mA    |
| I <sub>EBO</sub>       | Emitter Cut-off Current                | $V_{EB} = 3V, I_{C} = 0$                  |      | 0.1  | mA    |
| h <sub>FE</sub>        | * DC Current Gain                      | $V_{CE} = 10V, I_{C} = 50mA$              | 30   | 240  |       |

Pulse Test: PW≤300µs, Duty Cycle≤2%



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|--------------------------|---------------------------|---|
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